# **High Voltage Transistors**

## **NPN Silicon**

#### **Features**

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating		Symbol	Value	Unit
Collector - Emitter Voltage	MMBT5550 MMBT5551	V <sub>CEO</sub>	140 160	Vdc
Collector - Base Voltage	MMBT5550 MMBT5551	V <sub>CBO</sub>	160 180	Vdc
Emitter - Base Voltage		V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous		I <sub>C</sub>	600	mAdc
	Body Model achine Model	ESD	> 8000 > 400	٧

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @T <sub>A</sub> = 25°C Derate Above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) @T <sub>A</sub> = 25°C Derate Above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

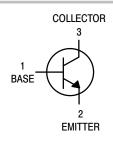
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



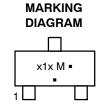
## ON Semiconductor®

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SOT-23 (TO-236) CASE 318 STYLE 6



x1x = Device Code

M1F = MMBT5550LT

G1 = MMBT5551LT

M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>				
MMBT5550LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel				
MMBT5550LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel				
MMBT5551LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel				
SMMBT5551LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel				
MMBT5551LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel				
SMMBT5551LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel				

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
1 (0 , D )	MBT5550 MBT5551	V <sub>(BR)CEO</sub>	140 160	- -	Vdc
	MBT5550 MBT5551	V <sub>(BR)CBO</sub>	160 180	-	Vdc
Emitter – Base Breakdown Voltage ( $I_E$ = 10 $\mu$ Adc, $I_C$ = 0)		V <sub>(BR)EBO</sub>	6.0	-	Vdc
(V <sub>CB</sub> = 120 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 100 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C)	MBT5550 MBT5551 MBT5550 MBT5551	I <sub>CBO</sub>	- - -	100 50 100 50	nAdc μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 4.0 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>	ı	50	nAdc
ON CHARACTERISTICS					
	MBT5550 MBT5551 MBT5550 MBT5551 MBT5550 MBT5551	h <sub>FE</sub>	60 80 60 80 20 30	- 250 250 - -	-
$(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$ M	oth Types MBT5550 MBT5551	V <sub>CE(sat)</sub>	- - -	0.15 0.25 0.20	Vdc
$(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$ M	oth Types MBT5550 MBT5551	V <sub>BE(sat)</sub>	- - -	1.0 1.2 1.0	Vdc
Collector Emitter Cut-off (V <sub>CB</sub> = 10 V) (V <sub>CB</sub> = 75 V)	oth Types	I <sub>CES</sub>	- -	50 100	nA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width = 300 µs, Duty Cycle = 2.0%.

## **TYPICAL CHARACTERISTICS**

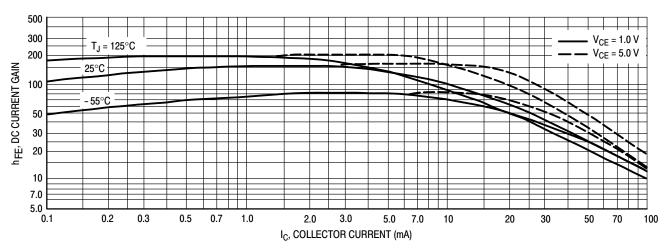


Figure 1. DC Current Gain

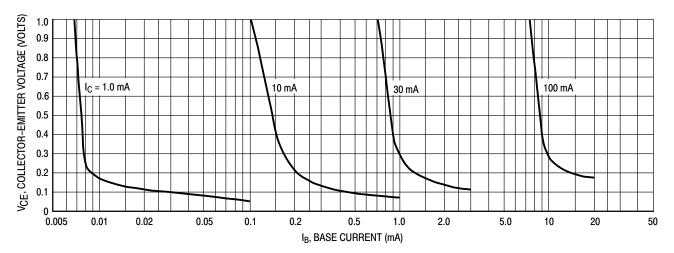


Figure 2. Collector Saturation Region

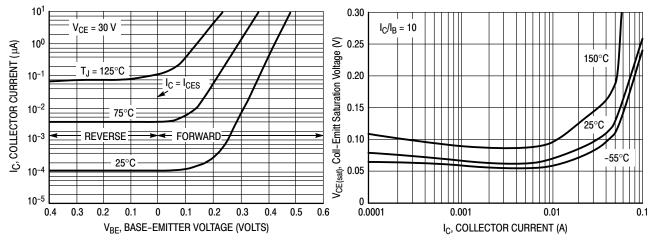
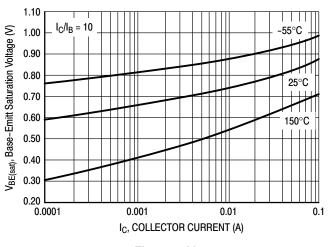


Figure 3. Collector Cut-Off Region

Figure 4. V<sub>CE(sat)</sub>

## **TYPICAL CHARACTERISTICS**



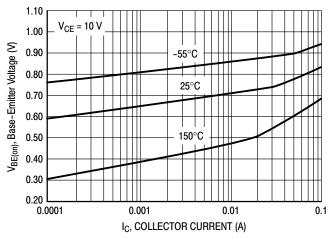
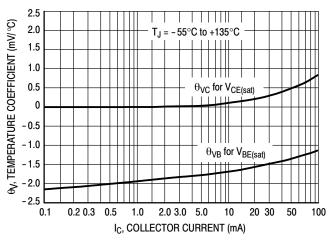


Figure 5. V<sub>BE(sat)</sub>

Figure 6. V<sub>BE(on)</sub>



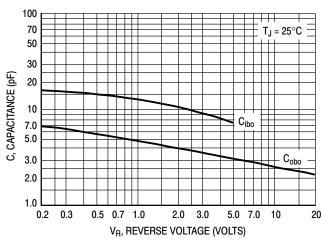
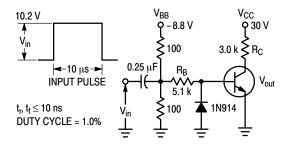


Figure 7. Temperature Coefficients

Figure 8. Capacitances



Values Shown are for  $I_{\mathbb{C}}$  @ 10 mA

Figure 9. Switching Time Test Circuit

## **TYPICAL CHARACTERISTICS**

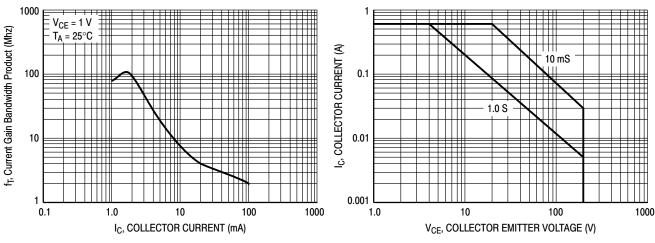


Figure 10. Current Gain Bandwidth Product



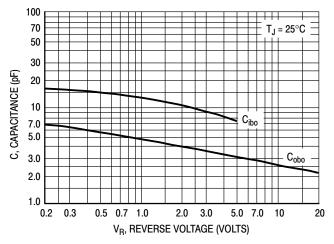


Figure 12. Capacitances

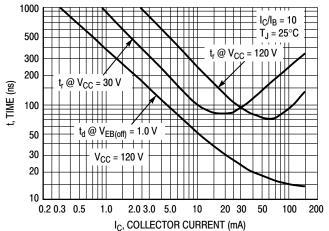
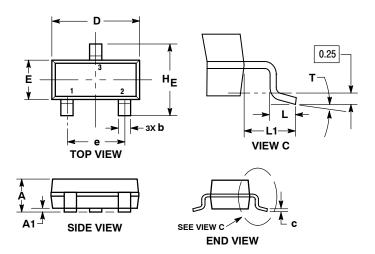


Figure 13. Turn-On Time

### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR** 



- NOTES.

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS.

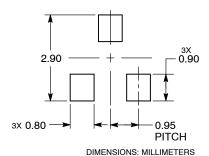
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10 °	0 °		10 °

STYLE 6: PIN 1. BASE

2. EMITTER

COLLECTOR

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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